

CORRECTION

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Correction: Theoretical investigations of the electronic and optical properties of a GaGeTe monolayer

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Correction for 'Theoretical investigations of the electronic and optical properties of a GaGeTe monolayer' by Nguyen Thi Han *et al.*, *RSC Adv.*, 2023, 13, 19464–19476, <https://doi.org/10.1039/D3RA03160H>.

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The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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